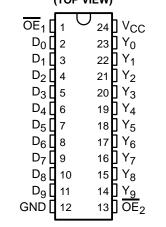
- **Function, Pinout, and Drive Compatible** With FCT, F, and AM29827 Logic
- Reduced V_{OH} (Typically = 3.3 V) Versions of Equivalent FCT Functions
- **Edge-Rate Control Circuitry for** Significantly Improved Noise Characteristics
- Ioff Supports Partial-Power-Down Mode Operation
- **ESD Protection Exceeds JESD 22**
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)
- **3-State Outputs**
- **Matched Rise and Fall Times**
- **Fully Compatible With TTL Input and Output Logic Levels**
- CY54FCT827T
 - 32-mA Output Sink Current
 - 12-mA Output Source Current
- CY74FCT827T
 - 64-mA Output Sink Current
 - 32-mA Output Source Current

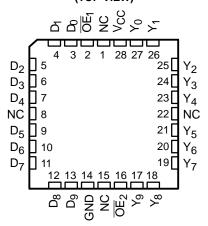
description

The 'FCT827T devices are 10-bit bus drivers that provide high-performance bus-interface buffering for wide data/address paths or buses carrying parity. The 10-bit buffers have NANDed output enables for maximum control flexibility. The 'FCT827T devices are designed high-capacitance-load drive capability, while providing low-capacitance bus loading at both inputs and outputs. All outputs are designed for low-capacitance bus loading high-impedance state.

CY74FCT827T . . . Q OR SO PACKAGE (TOP VIEW)



CY74FCT827T . . . L PACKAGE (TOP VIEW)



NC - No internal connection

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



ORDERING INFORMATION

| TA | PAC | (AGE† | SPEED (ns) | ORDERABLE PART NUMBER | TOP-SIDE MARKING |
|----------------|----------------|---------------|---------------|--------------------------|---------------------|
| | QSOP – Q | Tape and reel | 4.4 | FCT827C | |
| | SOIC - SO | Tube | 4.4 | CY74FCT827CTSOC | FCT827C |
| -40°C to 85°C | 3010 - 30 | Tape and reel | 4.4 | CY74FCT827CTSOCT | FC1627C |
| -40 C to 65 C | QSOP – Q | Tape and reel | 8 | CY74FCT827ATQCT | FCT827A |
| | SOIC - SO Tube | | 8 | CY74FCT827ATSOC | FCT827A |
| | 3010 - 30 | Tape and reel | 8 | CY74FCT827ATSOCT | FC1627A |
| −55°C to 125°C | LCC – L Tube | | 9 | CY54FCT827ATLMB | |

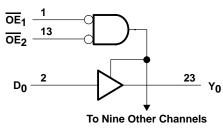
[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE

| | INPUTS | | OUTPUT | FUNCTION |
|-----------------|-----------------|---|--------|-------------|
| OE ₁ | OE ₂ | D | Υ | FUNCTION |
| L | L | L | L | Transparent |
| L | L | Н | Н | Transparent |
| Н | Х | Χ | Z | 2 atata |
| Х | Н | Χ | Z | 3-state |

H = High logic level, L = Low logic level, X = Don't care, Z = High-impedance state

logic diagram (positive logic)



Pin numbers shown are for the Q and SO packages.

absolute maximum rating over operating free-air temperature range (unless otherwise noted)‡

| Supply voltage range to ground potential | –0.5 V to 7 V |
|--|----------------|
| DC input voltage range | 0.5 V to 7 V |
| DC output voltage range | 0.5 V to 7 V |
| DC output current (maximum sink current/pin) | 120 mA |
| Package thermal impedance, θ _{JA} (see Note 1): Q package | 61°C/W |
| SO package | 46°C/W |
| Ambient temperature range with power applied, T _A | –65°C to 135°C |
| Storage temperature range, T _{stq} | –65°C to 150°C |

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The package thermal impedance is calculated in accordance with JESD 51-7.



recommended operating conditions (see Note 2)

| | | CY54FCT827T | | | CY7 | 7T | UNIT | |
|-----------------|--------------------------------|-------------|-----|-----|------|-----|------|------|
| | | MIN | NOM | MAX | MIN | NOM | MAX | UNIT |
| VCC | Supply voltage | 4.5 | 5 | 5.5 | 4.75 | 5 | 5.25 | V |
| VIH | High-level input voltage | 2 | | | 2 | | | V |
| V _{IL} | Low-level input voltage | | | 8.0 | | | 0.8 | V |
| ІОН | High-level output current | | | -12 | | | -32 | mA |
| l _{OL} | Low-level output current | | | 32 | | | 64 | mA |
| TA | Operating free-air temperature | -55 | | 125 | -40 | | 85 | °C |

NOTE 2: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| DADAMETED | | CT CONDITION | 10 | CY | 54FCT82 | 27T | CY | 74FCT82 | :7T | LINUT |
|------------------|--|-------------------------------|-------------------------------------|-----|------------------|------|-----|------------------|------|-------|
| PARAMETER | " | ST CONDITION | 15 | MIN | TYP [†] | MAX | MIN | TYP [†] | MAX | UNIT |
| \/ | V _{CC} = 4.5 V, | N = -18 mA | | | -0.7 | -1.2 | | | | V |
| VIK | $V_{CC} = 4.75 \text{ V}, I_{I}$ | N = -18 mA | | | | | | -0.7 | -1.2 | V |
| | $V_{CC} = 4.5 \text{ V},$ I | OH = −12 mA | | 2.4 | 3.3 | | | | | |
| Vон | V _{CC} = 4.75 V | OH = −32 mA | | | | | 2 | | | V |
| | VCC = 4.75 V | OH = −15 mA | | | | | 2.4 | 3.3 | | |
| VOL | $V_{CC} = 4.5 \text{ V},$ I | OL = 32 mA | | | 0.3 | 0.55 | | | | > |
| VOL | $V_{CC} = 4.75 \text{ V}, \qquad I_0$ | OL = 64 mA | | | | | | 0.3 | 0.55 | V |
| V_{hys} | All inputs | | | | 0.2 | | | 0.2 | | > |
| 1. | $V_{CC} = 5.5 \text{ V},$ | 'IN = VCC | | | | 5 | | | | μΑ |
| ΙΙ | $V_{CC} = 5.25 \text{ V}, $ V | 'IN = VCC | | | | | | | 5 | μΑ |
| lіН | $V_{CC} = 5.5 \text{ V}, $ | _{IN} = 2.7 V | | | | ±1 | | | | μΑ |
| 'IH | $V_{CC} = 5.25 \text{ V}, $ V | _{IN} = 2.7 V | | | | | | | ±1 | μΑ |
| I _{IL} | $V_{CC} = 5.5 \text{ V}, \qquad V$ | _{IN} = 0.5 V | | | | ±1 | | | | μΑ |
| 'IL | | _{IN} = 0.5 V | | | | | | | ±1 | μΛ |
| lozh | $V_{CC} = 5.5 \text{ V},$ | OUT = 2.7 V | | | | 10 | | | | μΑ |
| 'OZH | $V_{CC} = 5.25 \text{ V}, $ V | OUT = 2.7 V | | | | | | | 10 | μΑ |
| lozi | $V_{CC} = 5.5 \text{ V},$ V | OUT = 0.5 V | | | | -10 | | | | μΑ |
| IOZL | $V_{CC} = 5.25 \text{ V}, $ V | OUT = 0.5 V | | | | | | | -10 | μΑ |
| los‡ | | OUT = 0 V | | -60 | -120 | -225 | | | | mA |
| 105+ | $V_{CC} = 5.25 \text{ V}, $ V | OUT = 0 V | | | | | -60 | -120 | -225 | ША |
| l _{off} | | OUT = 4.5 V | | | | ±1 | | | ±1 | μΑ |
| loo | $V_{CC} = 5.5 \text{ V},$ | ' _{IN} ≤ 0.2 V, | $V_{IN} \ge V_{CC} - 0.2 \text{ V}$ | | 0.1 | 0.2 | | | | mA |
| lcc | $V_{CC} = 5.25 \text{ V}, $ V | ′ _{IN} ≤ 0.2 V, | $V_{IN} \ge V_{CC} - 0.2 \text{ V}$ | | | | | 0.1 | 0.2 | ША |
| Aloo | $V_{CC} = 5.5 \text{ V}, V_{IN} = 3.4$ | | | | 0.5 | 2 | | | | mA |
| ⊅ICC | $V_{CC} = 5.25 \text{ V}, V_{IN} = 3.25 \text{ V}$ | .4 V§, f ₁ = 0, Ou | tputs open | | | | | 0.5 | 2 | 1117 |

[†] Typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.



Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample-and-hold techniques are preferable to minimize internal chip heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output can raise the chip temperature well above normal and cause invalid readings in other parametric tests. In any sequence of parameter tests, IOS tests should be performed last.

[§] Per TTL-driven input (V_{IN} = 3.4 V); all other inputs at V_{CC} or GND

CY54FCT827T, CY74FCT827T 10-BIT BUFFERS WITH 3-STATE OUTPUTS

SCCS034A - SEPTEMBER 1994 - REVISED OCTOBER 2001

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted) (continued)

| DADAMETER | _ | TEGT CONDITIONS | | CY | 54FCT82 | 27T | CY | 74FCT82 | :7T | |
|----------------|--|---|--|-----|------------------|------|------|------------------|------|------|
| PARAMETER | | TEST CONDITIONS | | MIN | TYP [†] | MAX | MIN | TYP [†] | MAX | UNIT |
| ioon¶ | $\begin{array}{c} V_{CC} = 5.5 \text{ V, } \underline{One} \text{ input switching at 50\% duty cycle,} \\ \text{Outputs open, } \overline{OE}_1 \text{ or } \overline{OE}_2 = GND, \\ V_{IN} \leq 0.2 \text{ V or } V_{IN} \geq V_{CC} - 0.2 \text{ V} \\ \end{array}$ | | | | | | | | | mA/ |
| ICCD¶ | V_{CC} = 5.25 V, One in Outputs open, \overline{OE}_1 over $V_{IN} \le 0.2$ V or $V_{IN} \ge 0.2$ | or $\overline{OE}_2 = GND$, | | | | | 0.06 | 0.12 | MHz | |
| | | One bit switching at f ₁ = 10 MHz | $V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$ | | 0.7 | 1.4 | | | | |
| | $V_{CC} = 5.5 \text{ V},$ Outputs open, OE_1 or $OE_2 = GND$ | at 50% duty cycle | $V_{IN} = 3.4 \text{ V or GND}$ | | 1 | 2.4 | | | | |
| | | | $V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$ | | 1.6 | 3.2 | | | | |
| lc# | | at 50% duty cycle | V _{IN} = 3.4 V or GND | | 4.1 | 13.2 | | | | mA |
| I IC | | One bit switching at f ₁ = 10 MHz | $V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$ | | | | | 0.7 | 1.4 | IIIA |
| | V _{CC} = 5.25 V, | at 50% duty cycle | V _{IN} = 3.4 V or GND | | | | | 1 | 2.4 | |
| | Outputs open, OE ₁ or OE ₂ = GND | 10 bits switching at f ₁ = 2.5 MHz | $V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$ | | | | | 1.6 | 3.2 | |
| | at 50% duty cycle | | V _{IN} = 3.4 V or GND | | | | | 4.1 | 13.2 | |
| C _i | | | | | 5 | 10 | | 5 | 10 | pF |
| Co | | | | | 9 | 12 | | 9 | 12 | pF |

This parameter is derived for use in total power-supply calculations.

 $^{\#}$ IC = ICC + \triangle ICC × D_H × N_T + ICCD (f₀/2 + f₁ × N₁)

Where:

I_C = Total supply current

ICC = Power-supply current with CMOS input levels

 ΔI_{CC} = Power-supply current for a TTL high input (V_{IN} = 3.4 V)

D_H = Duty cycle for TTL inputs high N_T = Number of TTL inputs at D_H

I_{CCD} = Dynamic current caused by an input transition pair (HLH or LHL)

f₀ = Clock frequency for registered devices, otherwise zero

f₁ = Input signal frequency

N₁ = Number of inputs changing at f₁

All currents are in milliamperes and all frequencies are in megahertz.

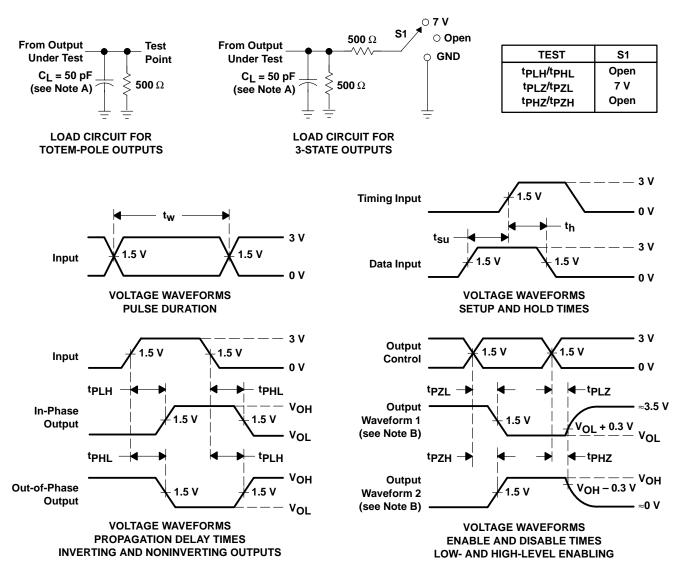
|| Values for these conditions are examples of the I_{CC} formula.



switching characteristics over operating free-air temperature range (see Figure 1)

| PARAMETER | FROM | то | TEST LOAD | CY54FC1 | 827AT | CY74FCT | 827AT | CY74FCT | 827CT | UNIT |
|------------------|---------|----------|--------------------------|---------|-------|---------|-------|---------|-------|------|
| PARAMETER | (INPUT) | (OUTPUT) | TEST LOAD | MIN | MAX | MIN | MAX | MIN | MAX | UNII |
| t _{PLH} | D | V | $C_L = 50 \text{ pF},$ | 1.5 | 9 | 1.5 | 8 | 1.5 | 4.4 | ns |
| t _{PHL} | ט | ī | $R_L = 500 \Omega$ | 1.5 | 9 | 1.5 | 8 | 1.5 | 4.4 | 115 |
| ^t PLH | D | V | C _L = 300 pF, | 1.5 | 17 | 1.5 | 15 | 1.5 | 10 | ns |
| ^t PHL | D | • | $R_L = 500 \Omega$ | 1.5 | 17 | 1.5 | 15 | 1.5 | 10 | 115 |
| ^t PZH | ŌE | Y | $C_L = 50 \text{ pF},$ | 1.5 | 13 | 1.5 | 12 | 1.5 | 7 | ns |
| tPZL | OL | ī | $R_L = 500 \Omega$ | 1.5 | 13 | 1.5 | 12 | 1.5 | 7 | 115 |
| ^t PZH | ŌE | ~ | C _L = 300 pF, | 1.5 | 25 | 1.5 | 23 | 1.5 | 14 | ns |
| ^t PZL | OE | • | $R_L = 500 \Omega$ | 1.5 | 25 | 1.5 | 23 | 1.5 | 14 | 115 |
| ^t PHZ | ŌE | Y | C _L = 5 pF, | 1.5 | 9 | 1.5 | 9 | 1.5 | 5.7 | ns |
| ^t PHL | 5 | 1 | $R_L = 500 \Omega$ | 1.5 | 9 | 1.5 | 9 | 1.5 | 5.7 | 115 |
| ^t PHZ | ŌĒ | Υ | $C_L = 50 \text{ pF},$ | 1.5 | 10 | 1.5 | 10 | 1.5 | 6 | ne |
| tPHL | OE . | ſ | $R_L = 500 \Omega$ | 1.5 | 10 | 1.5 | 10 | 1.5 | 6 | ns |

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_I includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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PACKAGING INFORMATION

| Orderable part number | Status | Material type | Package Pins | Package qty Carrier | RoHS (3) | Lead finish/ Ball material | MSL rating/ Peak reflow (5) | Op temp (°C) | Part marking (6) |
|-----------------------|--------|---------------|-----------------|-----------------------|-----------------|-------------------------------|-----------------------------------|--------------|---------------------|
| 5962-9224701M3A | Active | Production | LCCC (FK) 28 | 42 TUBE | No | SNPB | N/A for Pkg Type | -55 to 125 | 5962- 9224701M3A |
| CY74FCT827ATQCT | Active | Production | SSOP (DBQ) 24 | 2500 LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | FCT827A |
| CY74FCT827ATQCT.B | Active | Production | SSOP (DBQ) 24 | 2500 LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | FCT827A |
| CY74FCT827ATSOC | Active | Production | SOIC (DW) 24 | 25 TUBE | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | FCT827A |
| CY74FCT827ATSOC.B | Active | Production | SOIC (DW) 24 | 25 TUBE | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | FCT827A |
| CY74FCT827ATSOCT | Active | Production | SOIC (DW) 24 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | FCT827A |
| CY74FCT827ATSOCT.B | Active | Production | SOIC (DW) 24 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | FCT827A |
| CY74FCT827CTQCT | Active | Production | SSOP (DBQ) 24 | 2500 LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | FCT827C |
| CY74FCT827CTQCT.B | Active | Production | SSOP (DBQ) 24 | 2500 LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 85 | FCT827C |
| CY74FCT827CTSOC | Active | Production | SOIC (DW) 24 | 25 TUBE | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | FCT827C |
| CY74FCT827CTSOC.B | Active | Production | SOIC (DW) 24 | 25 TUBE | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | FCT827C |
| CY74FCT827CTSOCT | Active | Production | SOIC (DW) 24 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | FCT827C |
| CY74FCT827CTSOCT.B | Active | Production | SOIC (DW) 24 | 2000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | FCT827C |

⁽¹⁾ Status: For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PACKAGE OPTION ADDENDUM

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Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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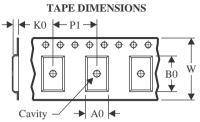
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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





| A0 | Dimension designed to accommodate the component width |
|----|---|
| В0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|------------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| CY74FCT827ATQCT | SSOP | DBQ | 24 | 2500 | 330.0 | 16.4 | 6.5 | 9.0 | 2.1 | 8.0 | 16.0 | Q1 |
| CY74FCT827ATSOCT | SOIC | DW | 24 | 2000 | 330.0 | 24.4 | 10.75 | 15.7 | 2.7 | 12.0 | 24.0 | Q1 |
| CY74FCT827CTQCT | SSOP | DBQ | 24 | 2500 | 330.0 | 16.4 | 6.5 | 9.0 | 2.1 | 8.0 | 16.0 | Q1 |
| CY74FCT827CTSOCT | SOIC | DW | 24 | 2000 | 330.0 | 24.4 | 10.75 | 15.7 | 2.7 | 12.0 | 24.0 | Q1 |



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*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| CY74FCT827ATQCT | SSOP | DBQ | 24 | 2500 | 353.0 | 353.0 | 32.0 |
| CY74FCT827ATSOCT | SOIC | DW | 24 | 2000 | 350.0 | 350.0 | 43.0 |
| CY74FCT827CTQCT | SSOP | DBQ | 24 | 2500 | 353.0 | 353.0 | 32.0 |
| CY74FCT827CTSOCT | SOIC | DW | 24 | 2000 | 350.0 | 350.0 | 43.0 |

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

| Device | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (µm) | B (mm) |
|-------------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| CY74FCT827ATSOC | DW | SOIC | 24 | 25 | 506.98 | 12.7 | 4826 | 6.6 |
| CY74FCT827ATSOC.B | DW | SOIC | 24 | 25 | 506.98 | 12.7 | 4826 | 6.6 |
| CY74FCT827CTSOC | DW | SOIC | 24 | 25 | 506.98 | 12.7 | 4826 | 6.6 |
| CY74FCT827CTSOC.B | DW | SOIC | 24 | 25 | 506.98 | 12.7 | 4826 | 6.6 |

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